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### Contents

**SESSION 1 PHOTOVOLTAICS I: ADVANCED CONCEPTS**

- **7933 03** Quantum wells in multiple junction photovoltaics (Invited Paper) [7933-02]
  T. N. D. Tibbits, M. P. Lumb, A. Dobbin, QuantaSol Ltd. (United Kingdom)

- **7933 05** Simulation of nipi photovoltaic devices [7933-04]
  M. A. Slocum, D. V. Forbes, Rochester Institute of Technology (United States); C. D. Cress, U.S. Naval Research Lab. (United States); S. Polly, S. M. Hubbard, Rochester Institute of Technology (United States)

**SESSION 2 SEMICONDUCTOR LASERS AND OPTICAL INJECTION EFFECTS**

- **7933 0A** Optical injection of quantum dash semiconductor lasers at 1550nm for tunable photonic oscillators (Invited Paper) [7933-09]
  M. Pochet, N. A. Naderi, The Univ. of New Mexico (United States); V. Kovanis, Air Force Research Lab. (United States); L. F. Lester, The Univ. of New Mexico (United States)

- **7933 0B** Polarization-resolved nonlinear dynamics in long-wavelength single-mode VCSELs subject to orthogonal optical injection [7933-10]
  P. Pérez, A. Quirce, L. Pesquera, A. Valle, Univ. de Cantabria (Spain)

- **7933 0D** Rate equation analysis of dynamic response in strongly injection-locked semiconductor microring lasers [7933-12]
  G. A. Smolyakov, M. Osiński, The Univ. of New Mexico (United States)

- **7933 0E** Influence of the linewidth enhancement factor on the modulation response of a nanostructure-based semiconductor laser operating under external optical feedback [7933-13]
  F. Grillot, Univ. Européenne de Bretagne, CNRS (France) and Institut Telecom, ParisTech, CNRS (France); N. Dubey, Indian Institute of Technology Guwahati (India)

**SESSION 3 PHOTOVOLTAICS II: MATERIALS**

- **7933 0G** Dilute nitride multi-quantum well multi-junction design: a route to ultra-efficient photovoltaic devices [7933-15]
  G. K. Vijaya, A. Alemu, A. Freundlich, Univ. of Houston (United States)

- **7933 0H** Carrier dynamics in MOVPE-grown bulk dilute nitride materials for multi-junction solar cells [7933-16]
  Y. Sin, S. LaLumondiere, The Aerospace Corp. (United States); T. Garrod, T. W. Kim, J. Kirch, L. Mawst, Univ. of Wisconsin-Madison (United States); W. T. Lotshaw, S. C. Moss, The Aerospace Corp. (United States)
Up-conversion luminescence enhancement in erbium-doped porous silicon photonic crystals for photovoltaics [7933-17]
C. M. Johnson, P. J. Reece, G. J. Conibeer, The Univ. of New South Wales (Australia)

Rigorous optical simulation of light management in crystalline silicon thin film solar cells with rough interface textures [7933-21]
D. Lockau, Helmholtz-Zentrum Berlin für Materialien und Energie GmbH (Germany) and Zuse-Institute Berlin (Germany); L. Zschiedrich, JCMwave GmbH (Germany); S. Burger, F. Schmidt, Zuse-Institute Berlin (Germany) and JCMwave GmbH (Germany); F. Ruske, B. Rech, Helmholtz-Zentrum Berlin für Materialien und Energie GmbH (Germany)

High efficiency triple-junction solar cells employing biomimetic antireflective structures [7933-22]
M.-Y. Chiu, C.-H. Chang, F.-Y. Chang, P. Yu, National Chiao Tung Univ. (Taiwan)

Modeling of radiation induced defects in space solar cells (Invited Paper) [7933-24]

Modeling and analysis of multijunction solar cells [7933-26]
M. González, Global Defense Technology & Systems, Inc. (United States); N. Chan, N. J. Ekins-Daukes, J. G. J. Adams, P. Stavrinou, Imperial College London (United Kingdom); I. Vurgaftman, J. R. Meyer, J. Abell, R. J. Walters, C. D. Cress, P. P. Jenkins, U.S. Naval Research Lab. (United States)

Resonant thermo-tunneling design for ultra-efficient nanostructured solar cells [7933-27]
A. Alemu, A. Freundlich, Univ. of Houston (United States)

Finite-element method simulations of high-Q nanocavities with 1D photonic bandgap [7933-28]
S. Burger, Zuse-Institute Berlin (Germany) and JCMwave GmbH (Germany); J. Pomplun, JCMwave GmbH (Germany); F. Schmidt, Zuse-Institute Berlin (Germany) and JCMwave GmbH (Germany); L. Zschiedrich, JCMwave GmbH (Germany)

Design of complex large-scale photonic integrated circuits (PICs) based on ring-resonator structures [7933-29]
C. Arellano, VPIsystems GmbH (Germany); S. Mingaleev, E. Sokolov, VPI Development Ctr. (Belarus); I. Koltchanov, A. Richter, VPIsystems GmbH (Germany)

Ultra wideband integrated polarization splitter/combiner using electro-optic effect in GaAs [7933-30]
M. A. Swillam, Univ. of Toronto (Canada); M. H. Bakr, X. Li, McMaster Univ. (Canada)
Analysis of thermoelectric properties of AlInN semiconductor alloys [7933-32]
J. Zhang, H. Tong, J. A. Herbsommer, N. Tansu, Lehigh Univ. (United States)

SESSION 7 QUANTUM DOT AND QUANTUM DASH DEVICES

Modeling and simulation of nanocrystal solids with rate equations [7933-36]
O. Cellek, ASELSAN Inc. (Turkey); M. Law, Univ. of California, Irvine (United States)

Modeling the temperature performance of monolithic passively mode-locked quantum dot lasers [7933-37]
M. T. Crowley, D. Murrell, N. Patel, The Univ. of New Mexico (United States); M. Breivik, Norwegian Univ. of Science and Technology (Norway); C.-Y. Lin, Y. Li, The Univ. of New Mexico (United States); B.-O. Finland, Norwegian Univ. of Science and Technology (Norway); L. F. Lester, The Univ. of New Mexico (United States)

Investigation of spectral responsivity of InAs QD-embedded GaAs solar cells [7933-38]
C. G. Bailey, D. V. Forbes, NanoPower Research Lab. (United States); R. P. Raffaelle, National Renewable Energy Lab. (United States); S. M. Hubbard, NanoPower Research Lab. (United States)

SESSION 8 PHYSICS AND SIMULATION OF LIGHT EMITTING DIODES

Optical properties of individual GaN nanorods for light emitting diodes: influence of geometry, materials, and facets [7933-39]
C. Kölper, OSRAM Opto Semiconductors GmbH (Germany) and Univ. Kassel (Germany); M. Sabathil, OSRAM Opto Semiconductors GmbH (Germany); B. Witzigmann, F. Römer, Univ. Kassel (Germany); W. Bergbauer, M. Strassburg, OSRAM Opto Semiconductors GmbH (Germany)

Transport equation model for the optics of light-emitting diodes with arbitrary surface microstructure [7933-40]
O. Heikilä, J. Oksanen, J. Tulkki, Aalto Univ. (Finland)

Numerical study on efficiency droop of blue InGaN light-emitting diodes [7933-42]
Y.-K. Kuo, J.-Y. Chang, J.-D. Chen, National Changhua Univ. of Education (Taiwan)

SESSION 9 ELECTROMAGNETIC ANALYSIS OF RESONATORS AND GRATINGS

The pole condition as transparent boundary condition for resonance problems: detection of spurious modes [7933-46]
B. Kettner, F. Schmidt, Zuse-Institute Berlin (Germany)

Similar structures, different characteristics: optical performances of circular polarizers with single-, double-, and multi-helical metamaterials [7933-47]
Z. Yang, M. Zhao, P. Lu, Huazhong Univ. of Science and Technology (China)
SESSION 10  SEMICONDUCTOR LASERS

7933 1D Analogue modulation performance of 20 GHz vertical cavity surface emitting lasers for radio over fiber applications (Invited Paper) [7933-48]
M. J. Crisp, Z. Qureshi, J. D. Ingham, R. V. Penty, I. H. White, Univ. of Cambridge (United Kingdom); N. N. Ledentsoy, J. A. Lott, VI Systems GmbH (Germany)

7933 1G Giant lasing effect in magnetic point contacts and its detection by DC electrical measurements [7933-51]
A. M. Kadigrobov, Univ. of Gothenburg (Sweden) and Ruhr-Univ. Bochum (Germany); R. I. Shchekhter, Univ. of Gothenburg (Sweden); S. I. Kulinich, B.I. Verkin Institute for Low Temperature Physics and Engineering (Ukraine); M. Jonson, Univ. of Gothenburg (Sweden) and Heriot-Watt Univ. (United Kingdom) and Konkuk Univ. (Korea, Republic of)

SESSION 11  NONLINEAR DYNAMICS AND MODE-LOCKING OF SEMICONDUCTOR LASERS I

7933 1I Modulation effects in multi-section semiconductor lasers (Invited Paper) [7933-52]
N. G. Usechak, M. Grupen, Air Force Research Lab. (United States); N. Naderi, Y. Li, L. F. Lester, The Univ. of New Mexico (United States); V. Kovanis, Air Force Research Lab. (United States)

7933 1J Mode-locking theory for ultra-short few-femtosecond laser pulses [7933-53]
E. Farnum, Kean Univ. (United States); J. N. Kutz, Univ. of Washington (United States)

7933 1K Four-wave mixing analysis of quantum dot and quantum well lasers [7933-54]
H.-H. Lin, C.-H. Lin, F.-Y. Lin, National Tsing Hua Univ. (Taiwan)

7933 1L Characterizing and suppressing multi-pulsing instabilities in mode-locked lasers [7933-55]
E. Shlizerman, E. Ding, M. O. Williams, J. N. Kutz, Univ. of Washington (United States)

7933 1M Noise suppressions in synchronized chaotic lidars [7933-56]
Y.-H. Liao, W.-T. Wu, F.-Y. Lin, National Tsing Hua Univ. (Taiwan)

SESSION 12  NONLINEAR DYNAMICS OF SEMICONDUCTOR LASERS II

7933 1O Oscillation frequency shifts observed in vertical cavity surface emitting lasers exposed to magnetic fields [7933-58]
T. Kobayashi, Y. Yamagishi, H. Arai, Y. Matsumoto, T. Sato, M. Ohkawa, Niigata Univ. (Japan)

7933 1P New modeling of laterally coupled diode lasers: analysis and comparison with experimental results [7933-59]
B. González, H. Lamela, R. Santos, Carlos III Univ. of Madrid (Spain)

7933 1Q Compression performance of a NOLM including a SOA for pulse shaping of gain switching diode lasers: influence of the alpha factor [7933-60]
C. de Dios, H. Lamela, Carlos III Univ. of Madrid (Spain)
## SESSION 13 PHOTODETECTORS

7933 1R **Modeling of afterpulsing in single-photon avalanche diodes** [7933-61]
M. Anti, A. Tosi, F. Acerbi, F. Zappa, Politecnico di Milano (Italy)

7933 1S **Determination of internal quantum efficiency of a photodetector through its voltage-current characteristics** [7933-62]
A. Mikryukov, A. Koval’ev, A. A. Liberman, S. Moskaluk, All-Russian Research Institute for Optical and Physical Measurement (Russian Federation)

## SESSION 14 DEVICES FOR QUANTUM COMMUNICATIONS: JOINT SESSION WITH CONFERENCE 7948

7933 1U **A light emitting diode for entangled photons (Invited Paper)** [7933-64]
R. M. Stevenson, Toshiba Research Europe Ltd. (United Kingdom); C. L. Salter, Toshiba Research Europe Ltd. (United Kingdom) and Univ. of Cambridge (United Kingdom); I. Farrer, C. A. Nicoll, D. A. Ritchie, Univ. of Cambridge (United Kingdom); A. J. Shields, Toshiba Research Europe Ltd. (United Kingdom)

7933 1V **Modeling the evolution of quantum optical states in optoelectronic devices** [7933-65]
T. Häyrynen, J. Oksanen, J. Tulkki, Aalto Univ. (Finland)

7933 1W **High Q photonic crystal cavities with tapered air holes** [7933-66]
F. S. F. Brossard, Hitachi Cambridge Lab. (United Kingdom); S. G. Schirmer, Univ. of Cambridge (United Kingdom); A. R. A. Chalcraft, D. M. Whittaker, The Univ. of Sheffield (United Kingdom)

7933 1X **Electrically pumped photonic nanowire single-photon source with an efficiency of 89%** [7933-67]
N. Gregersen, T. R. Nielsen, J. Mørk, Technical Univ. of Denmark (Denmark); J. Claudon, J.-M. Gérard, CEA-CNRS Nanophysique et Semiconducteurs (France)

## POSTER SESSION

7933 1Y **Top transmission grating GaN LED simulations for light extraction improvement** [7933-68]
S. Trieu, X. Jin, California Polytechnic State Univ., San Luis Obispo (United States) and Peking Univ. (China); A. Ellaboudy, California Polytechnic State Univ., San Luis Obispo (United States); B. Zhang, X.-N. Kang, G.-Y. Zhang, X. Chang, W. Wei, S. Y. Jian, F. X. Xing, Peking Univ. (China)

7933 1Z **Influence of pressure on optical absorption of triglycine selenium single crystals** [7933-69]
K. Ozga, I. V. Kityk, Czestochowa Univ. of Technology (Poland); J. Owisk, Military Univ. of Technology (Poland); J. Berdowski, J. Długosz Univ, de Czestochowa (Poland); Z. Tyliczynski, Adam Mickiewicz Univ. (Poland); A. Wojciechowski, A. Ślęzak, Czestochowa Univ. of Technology (Poland); A. Rembielińska, LOT Polish Airlines (Poland)

7933 20 **Design and theoretical characteristics of directional coupler-type optical polarization splitters using dielectric periodic multilayers** [7933-70]
K. Baba, T. Nakai, Sendai National College of Technology (Japan)
<table>
<thead>
<tr>
<th>Page</th>
<th>Title</th>
<th>Authors</th>
</tr>
</thead>
<tbody>
<tr>
<td>7933 22</td>
<td>Demonstration of arbitrary channel selection utilizing a pulse-injected double phase-locked semiconductor laser</td>
<td>Y.-S. Juan, F.-Y. Lin, National Tsing Hua Univ. (Taiwan)</td>
</tr>
<tr>
<td>7933 23</td>
<td>Energy enhancement in mode-locked lasers using sinusoidal transmission functions for saturable absorption</td>
<td>E. Ding, E. Shlizerman, J. N. Kutz, Univ. of Washington (United States)</td>
</tr>
<tr>
<td>7933 24</td>
<td>Qualitative analysis of ultra-short optical dissipative solitary pulses in the actively mode-locked semiconductor heterolasers with an external fiber cavity</td>
<td>A. S. Shcherbakov, National Institute for Astrophysics, Optics and Electronics (Mexico); J. Campos Acosta, Institute for Applied Physics (Spain); P. Moreno Zarate, National Institute for Astrophysics, Optics and Electronics (Mexico) and Nova Univ. (Mexico); A. Pons Aglio, Institute for Applied Physics (Spain)</td>
</tr>
<tr>
<td>7933 25</td>
<td>Simulation of hot electron quantum well photovoltaic devices</td>
<td>H. Z. Fardi, Univ. of Colorado Denver (United States)</td>
</tr>
<tr>
<td>7933 27</td>
<td>Rapidly optimizing optoelectronic devices using full wave 3D simulation software</td>
<td>I. Bendoym, N. Pishbin, E. Lansey, D. T. Crouse, The City College of New York (United States)</td>
</tr>
<tr>
<td>7933 29</td>
<td>Enhanced efficiency of organic solar cells with silver nanowire electrodes</td>
<td>T. Xu, M.-G. Kang, H.-J. Park, L. J. Guo, Univ. of Michigan, Ann Arbor (United States)</td>
</tr>
<tr>
<td>7933 2A</td>
<td>Polarization characteristics of plasmonics-based optical waveguides for polarization rotation</td>
<td>H.-S. Kim, T.-K. Lee, G.-Y. Oh, Y.-W. Choi, Chung-Ang Univ. (Korea, Republic of)</td>
</tr>
<tr>
<td>7933 2C</td>
<td>2×2 photonic crystal fiber splitter for 800 nm spectral domain optical coherence tomography</td>
<td>J. B. Eom, Gwangju Institute of Science and Technology (Korea, Republic of) and Korea Photonics Technology Institute (Korea, Republic of); E. J. Min, M. J. Ju, S. J. Lee, K. S. Park, Gwangju Institute of Science and Technology (Korea, Republic of); J.-H. Park, Korea Photonics Technology Institute (Korea, Republic of); B. H. Lee, Gwangju Institute of Science and Technology (Korea, Republic of)</td>
</tr>
<tr>
<td>7933 2F</td>
<td>Super fast physical-random number generation using laser diode frequency noises</td>
<td>T. Ushiki, K. Doi, S. Maehara, T. Sato, M. Ohkawa, Y. Ohdaira, Niigata Univ. (Japan)</td>
</tr>
<tr>
<td>7933 2G</td>
<td>Modeling and optimal designs for dislocation and radiation tolerant single and multijunction solar cells</td>
<td>A. Mehrotra, A. Alemu, A. Freundlich, Univ. of Houston (United States)</td>
</tr>
<tr>
<td>7933 2J</td>
<td>1550 nm DFB semiconductor lasers with high power and low noise</td>
<td>Y.-G. Zhao, A. Nikolov, R. Dutt, APIC Corp. (United States)</td>
</tr>
<tr>
<td>7933 2K</td>
<td>Modeling and design particularities for distributed feedback lasers with laterally-coupled ridge-waveguide surface gratings</td>
<td>A. Laakso, J. Karinen, M. Dumitrescu, Tampere Univ. of Technology (Finland)</td>
</tr>
</tbody>
</table>
Indium-tin-oxide nanowhiskers crystalline silicon photovoltaics combining micro- and nano-scale surface textures [7933-95]
C. H. Chang, M. H. Hsu, National Chiao Tung Univ. (Taiwan); W. L. Chang, W. C. Sun, Industrial Technology Research Institute (Taiwan); P. Yu, National Chiao Tung Univ. (Taiwan)

Design of simultaneous bidirectional CMOS transceiver with a resistor-transconductor hybrid for optical chip-to-chip interconnects [7933-96]

Author Index
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Photovoltaics I: Advanced Concepts
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Minisymposium Fundamentals of Hybrid Optoelectronics
Sven Burger, Konrad-Zuse-Zentrum für Informationstechnik Berlin (Germany)

Semiconductor Lasers and Optical Injection Effects
David G. Lidzey, The University of Sheffield (United Kingdom)

Photovoltaics II: Materials
Vassillios I. Kovanis, Air Force Research Laboratory (United States)

Photovoltaics III: Optical Design
Pavlos G. Lagoudakis, University of Southampton (United Kingdom)

Photovoltaics IV: Physics and Simulation
Alexandre Freundlich, University of Houston (United States)

Integrated Optoelectronics
Alexey V. Maslov, Canon U.S.A., Inc. (United States)

Quantum Dot and Quantum Dash Devices
Tom N. D. Tibbits, QuantaSol Ltd. (United Kingdom)

Physics and Simulation of Light Emitting Diodes
Joachim Piprek, NUSOD Institute LLC (United States)

Electromagnetic Analysis of Resonators and gratings
Mark R. Stevenson, Toshiba Research Europe Ltd. (United Kingdom)

Semiconductor Lasers
Stephan W. Koch, Philipps-Universität Marburg (Germany)

Nonlinear Dynamics and Mode-Locking of Semiconductor Lasers I
Yohan Barbarin, ETH Zürich (Switzerland)

Nonlinear Dynamics of Semiconductor Lasers II
Frank Jahnke, Universität Bremen (Germany)

Photodetectors
Michael Lorke, Technical University of Denmark (Denmark)
Devices for Quantum Communications:
Joint Session with Conference 7948
*Marek Osinski*, The University of New Mexico (United States)